








	<h2 style="color: red;">FQU3N60TU</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQU3N60TU</a></p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 600V 2.4A IPAK</p> <p><b>Datenblätter:</b> <a href="#">1.FQU3N60TU.pdf</a> <a href="#">2.FQU3N60TU.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 3400 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQU3N60TU
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 600V 2.4A IPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	3400 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	2.5W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.4A (Tc)
Rds On (Max) @ Id, Vgs	3.6 Ohm @ 1.2A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	450pF @ 25V
Verpackung	Tube

FQU3N60TU ist neu im Original, Suche FQU3N60TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQU3N60TU Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQU3N60TU: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQU3N60C</b> FSC FQU3N60C FSC</p>	 <p><b>FQU3N60CTU</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 2.4A IPAK</p>	 <p><b>FQU3N60TU</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 2.4A IPAK</p>	 <p><b>FQU3N50CTU</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 2.5A IPAK</p>
 <p><b>FQU3N60CTU</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 2.4A IPAK</p>	 <p><b>FQU3P20TU</b> Fairchild/ON Semiconductor MOSFET P-CH 200V 2.4A IPAK</p>	 <p><b>FQU3P50</b> FAIRCHILD FQU3P50 FAIRCHILD</p>	 <p><b>FQU3P20TU</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 2.4A IPAK</p>

### heiße Teile

Mehr

<a href="#">FQU20N06</a>	<a href="#">FQU20N06L</a>	<a href="#">FQU20N06LTU</a>	<a href="#">FQU20N06LTU</a>	<a href="#">FQU2N50B</a>
<a href="#">FQU2N50BTU</a>	<a href="#">FQU2N50BTU</a>	<a href="#">FQU2N60/SSU2N60</a>	<a href="#">FQU2N60A</a>	<a href="#">FQU2N60B</a>
<a href="#">FQU2N60C</a>	<a href="#">FQU2N60CTU</a>	<a href="#">FQU2N60CTU</a>	<a href="#">FQU2N65C</a>	<a href="#">FQU2N90TU</a>
<a href="#">FQU2N90TU</a>	<a href="#">FQU30N06L</a>	<a href="#">FQU3N40TU</a>	<a href="#">FQU3N40TU</a>	<a href="#">FQU3N50C</a>
<a href="#">FQU3N50CTU</a>	<a href="#">FQU3N50CTU</a>	<a href="#">FQU3N60C</a>	<a href="#">FQU3N60CTU</a>	<a href="#">FQU3N60CTU</a>
<a href="#">FQU3N60TU</a>	<a href="#">FQU4N20LTU</a>	<a href="#">FQU4N20TU</a>	<a href="#">FQU4N20TU</a>	<a href="#">FQU4N25TU</a>
<a href="#">FQU4N25TU</a>	<a href="#">FQU4N50TU</a>	<a href="#">FQU4N50TU</a>	<a href="#">FQU4N50TU_WS</a>	<a href="#">FQU4N60C</a>
<a href="#">FQU4P25TU</a>	<a href="#">FQU4P25TU</a>	<a href="#">FQU5N40TU</a>	<a href="#">FQU5N40TU</a>	<a href="#">FQU5N50C</a>
<a href="#">FQU5N50CS</a>	<a href="#">FQU5N50CTU</a>	<a href="#">FQU5N50CTU</a>	<a href="#">FQU5N60C</a>	<a href="#">FQU5N60CTU</a>
<a href="#">FQU5N60CTU</a>	<a href="#">FQU5N65C</a>	<a href="#">FQU5P20TU</a>	<a href="#">FQU5P20TU</a>	<a href="#">FQU6N40C</a>

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